

JUN. 4. 2004 4:05PM  
TO:USPTO (GENERAL)

NO. 967 P. 1/7

## **BEYER WEAVER & THOMAS, LLP**

INTELLECTUAL PROPERTY LAW  
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### **FACSIMILE COVER SHEET**

May 26, 2004

**Receiver:** Maldonado, Julio J. – Art Unit 2823  
(USPTO Central Fax)

**FAX # :** 703-872-9306

**Sender:** Leslie Russell, Patent Secretary for:  
Roger S. Sampson

**Our Ref. No.:** NOVLP074/NVLS-000414

**Application No:** 09/998,993

**Re:** Response C

**Pages Including Cover Sheet(s):** 7

**Fax Contents:** Fax Cover Sheet – 1 Page  
Amendment Transmittal 1 Page  
Response C – 5 Pages

#### **MESSAGE:**

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#### **CONFIDENTIALITY NOTE**

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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

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In re application of: Turner et al.

Attorney Docket No.: NOVLP074/NVLS-000414

Application No.: 09/998,993

Examiner: Maldonado, Julio J.

Filed: November 15, 2001

Group: 2823

Title: PHOSPHOROUS-DOPED SILICON  
DIOXIDE PROCESS TO CUSTOMIZE  
ETCH PROFILES

**CERTIFICATE OF FACSIMILE TRANSMISSION**

I hereby certify that this correspondence is being transmitted by facsimile to fax to Examiner Maldonado, Julio J. at number 703-872-9306 to the U.S. Patent and Trademark Office on June 4, 2004.

Signed: \_\_\_\_\_

Leslie Russell

**AMENDMENT TRANSMITTAL**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Transmitted herewith is an Amendment in the above-identified application.  
The fee has been calculated as shown below.

	Claims After Amendment		Highest Previously Paid For	Present Extra	Small Entity Rate Fee	Large Entity Rate Fee
Total Claims	25	MINUS	25	0	x 9 =	x 18 = 0
Independent Claims	5	MINUS	5	0	x 43 =	x 86 = 0
Multiple Dependent Claim Present and Fee Not Previously Paid					\$145.00	\$290.00
<b>Total</b>					<b>\$</b>	<b>\$0</b>

☒ Applicant(s) believe that no (additional) Extension of Time is required; however, if it is determined that such an extension is required, Applicant(s) hereby petition that such an extension be granted and authorize the Commissioner to charge the required fees for an Extension of Time under 37 CFR 1.136 to Deposit Account No. 500388.

☒ Please charge the required fees, or any additional fees required to facilitate filing the enclosed response, to Deposit Account No. 500388 (Order No. NOVLP074).

Respectfully submitted,  
BEYER WEAVER & THOMAS, LLP

Roger S. Sampson  
Reg. No. 44,314

P.O. Box 778  
Berkeley, CA 94704-0778

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of: Turner et al.

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Patent and Trademark Office on June 4, 2004.

Signed: \_\_\_\_\_

*Leslie Russell*  
Leslie Russell

**RESPONSE C**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

This paper is submitted in response to the Office Action dated April 26, 2004 ("Office Action").

Remarks/Arguments begin on page 2 of this paper.